

SINGLE PHASE GLASS PASSIVATED BRIDGE RECTIFIER

029 (0.74)

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0.195 (4.95) 0.179 (4.55) 0.272 (6.90)

0.038 (0.95)

0.205 (5.2

0.008 (0.20

0.117 (2.97

0.058 (1.47)

0.049 (1.24)

0.062 (1.57)

MBS

0.018 (0.46

MD2S THRU	MD10S	VOLTAGE RANGE	50 to 1000 Volts	
MD25 IIIKU		CURRENT	0.5 Ampere	

### FEATURES

- UL recognized
- High forward surge current capability
- Glass passivated chip junction
- High temperature soldering guaranteed: 260°C / 10 seconds

#### MECHANICAL DATA

- Case: Transfer molded plastic
- Epoxy: UL 94V-0 rate flame retardant/
- Terminal: Lead solderable per MIL-STD-750 method 2026
- Polarity: Polarity symbols marked on case
- Mounting: any
- Weight: 0.0078 ounce, 0.22 gram

# MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

- Ratings at 25°C ambient temperature unless otherwise specified
- Single Phase, half wave, 60Hz, resistive or inductive load
- For capacitive load derate current by 20%

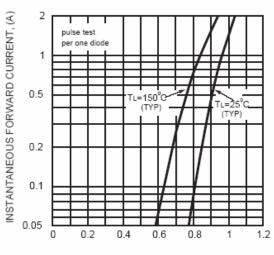
	SYMBOLS	MB2S	MB4S	MB6S	MB8S	MB10S	UNIT
Maximum Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	200	400	600	800	1000	Volts
Maximum RMS Voltage	V <sub>RMS</sub>	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	V <sub>DC</sub>	200	400	600	800	1000	Volts
Maximum Average Forward Rectified Current, T <sub>A</sub> = 30 °C On Glass–epoxy PCB (Note 1) On Aluminum substrate (Note 2)	I <sub>(AV)</sub>	0.5 0.8					Amps
Peak Forward Surge Current				0.0			
8.3mS single half sine wave superimposed on	I <sub>FSM</sub>	30					Amps
rated load (JEDEC method)							
Rating for Fusing (t<8.3mS)	I <sup>2</sup> t	5					$A^2s$
Maximum Instantaneous Forward Voltage drop per Bridge element0.4A	V <sub>F</sub>	1.00					Volts
Maximum DC Reverse Current at Rated $T_A = 25 \ ^{\circ}C$	I <sub>R</sub>	5.0					μA
DC Blocking Voltage per element $T_A = 125 \ ^{O}C$		100					
Typical Junction Capacitance Per leg (Measured at 1.0MHz and applied reverse voltage of 4.0V)	C <sub>J</sub>	13					pF
Typical Thermal Resistance (Note 1)	$R_{\theta Ja}$	85					<sup>o</sup> C/W
Operating Junction Temperature Range	TJ	(-55 to +150)					°C
Storage Temperature Range	T <sub>STG</sub>	(-55 to +150)					°C

#### Notes:

- 1. On glass epoxy PCB mounted on 0.05" x 0.05" (1.3mm x 1.3mm) copper pads
- Ohn aluminum substrage PCB with an area of 0.8" x 0.8" x 0.25" (20mm x 20mm x 6.4mm) mounted on 0.05" x 0.05" (1.3mm x 1.3mm) solder pad



## **RATINGS AND CHARACTERISTIC CURVES MBS2S THRU MBS10S**

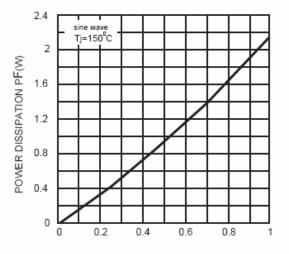


TYPICAL INSTANTANEOUS FORWARD

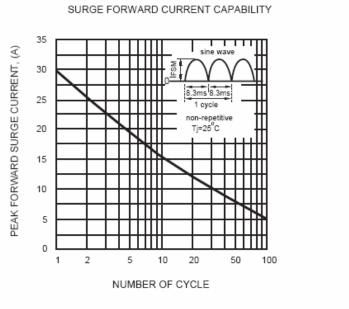
CHARACTERISTICS

INSTANTANEOUS FORWARD VOLTAGE, (V)

#### POWER DISSIPATION



AVERAGE RECTIFIED FORWARD CURRENT, Io (A)



TYPICAL FORWARD CURRENT DERATING CURVE

